Supplementary Information for

Enhanced thermoelectric performance of higher manganese silicides by shock-induced high dense dislocations

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Figure S1. (a) The size of the SPS sample and the steel holder. (b) The structure of the holder and the pre-press process.



Figure S2. The schematic diagram of shock compression experiment.



Figure S3. TEM image of a typical grain boundary



Figure S4. Temperature dependence of the thermal diffusivity



Figure S5. Temperature dependence of the heat capacity



Figure S6. The power factors of the HMS, SPS and SW samples, respectively

	ρ	σ	S	R _h	р	μ_{H}	m*/m ₀
	g/cm ³	S/cm	μV/K	10 ⁻⁹ m ³ /C	$10^{21}/cm^3$	$cm^2V^{-1} s^{-1}$	
HMS	4.86	443	116.9	3.54	1.764	1.57	9.3
SPS	4.99	910	100.6	2.41	2.596	1.34	10.2
SW	4.89	838	107.8	2.40	2.583	1.13	10.9

 Table S1. The parameters for the samples at 300K